JST136K-600T 4A TRIAC Rev.A.1.1 .52 795

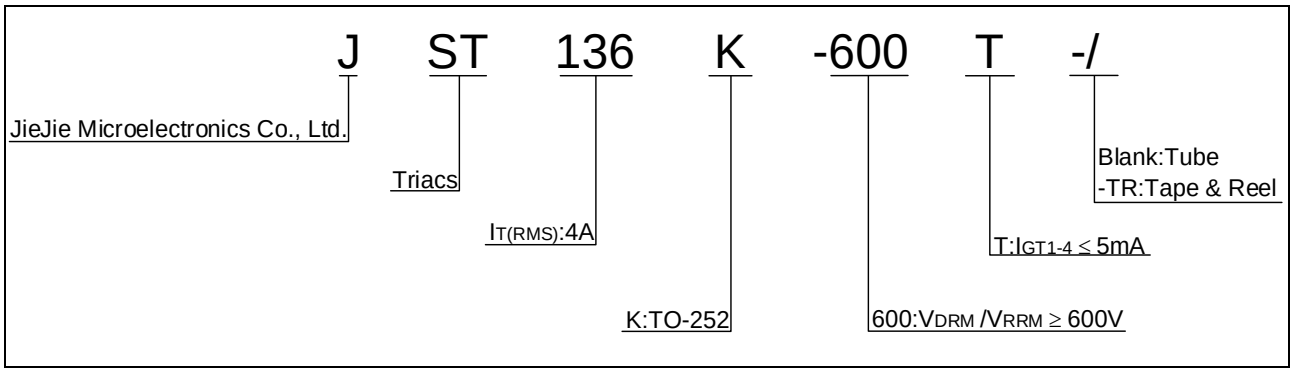
ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D=12V R_L=33Ω	ALL	MAX.	5	mA
V_{GT}		ALL	MAX.	1	V
V_{GD}	V_D=V_{DRM} T_j=125 R_L=3.3kΩ	ALL	MIN.	0.2	V
I_L	I_G=1.2I_{GT}	-	MAX.	10	mA
		-		15	
I_H	I_T=100mA		MAX.	5	mA
dV/dt	V_D=400V Gate Open T_j=110		MIN.	30	V/μs
(dV/dt)c	(dI/dt)c=1.8A/ms, T_j=110		MIN.	1	V/μs
t_{on}	I_G=10mA I_A=200mA I_R=20mA T_j=25		TYP.	1	μs
t_{off}				12	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM}=5A t_p=380μs	T_j=25	1.7	V
V_{TO}	Threshold voltage	T_j=125	1.	

ORDERING INFORMATION



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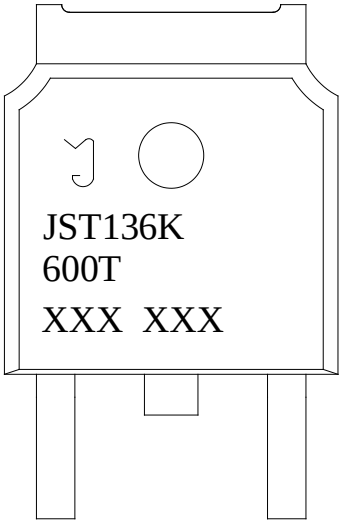

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FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

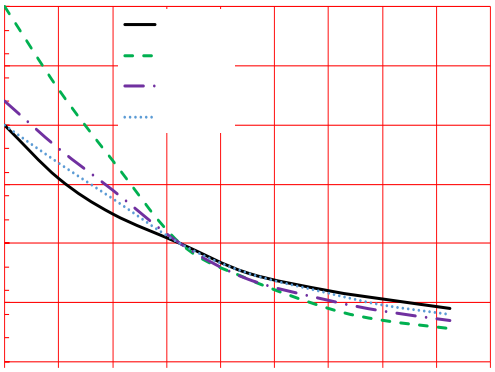

FIG.8 Test circuit for inductive and resistive loads to

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